

isc Silicon NPN Power Transistor

2SD907

DESCRIPTION

- High Collector Current
- Good Linearity of h_{FE}
- High Reliability
- Wide Area of Safe Operation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

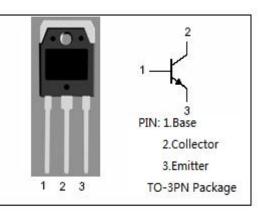
- Audio amplifier
- · Series regulators
- General purpose power amplifiers

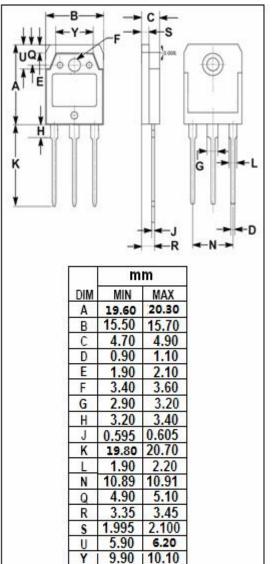
ABSOLUTE MAXIMUM RATINGS/T.=25 m

| ABSOLUTE MAXIMUM RATINGS(Ta=25°C) | | | | | | |
|-----------------------------------|---|---------|------|--|--|--|
| SYMBOL | PARAMETER | VALUE | UNIT | | | |
| V _{CBO} | Collector-Base Voltage | 80 | V | | | |
| V _{CEO} | Collector-Emitter Voltage 80 | | V | | | |
| V _{EBO} | Emitter-Base voltage | 7 | V | | | |
| lc | Collector Current-Continuous | 10 | A | | | |
| IB | Base Current-Continuous | 1.5 | А | | | |
| Pc | Collector Power Dissipation @ $T_c=25^{\circ}C$ | 80 | W | | | |
| TJ | Junction Temperature | 150 | °C | | | |
| T _{stg} | Storage Temperature Range | -55~150 | °C | | | |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | МАХ | UNIT |
|---------------------|-------------------------------------|-----|------|
| R _{th j-c} | Thermal Resistance,Junction to Case | | °C/W |





isc website: <u>www.iscsemi.com</u>



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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^{\circ}\!\!\!^{\circ}\!\!^{\circ}\!\!\!^{\circ}$ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | МАХ | UNIT |
|-----------------------------|--------------------------------------|--|-----|------|-----|------|
| V _{(BR)CEO} | Collector-Emitter Breakdown Voltage | I _C = 10mA; I _B = 0 | 80 | | | V |
| V _{(BR)CBO} | Collector-Base Breakdown Voltage | l _c = 0.1mA; l _E = 0 | 80 | | | V |
| V _{(BR)EBO} | Emitter-Base Breakdown Voltage | I _E = 0.1mA; I _C = 0 | 7 | | | V |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = 5A; I _B = 0.5A | | | 1.2 | V |
| $V_{\text{BE}(\text{sat})}$ | Base-Emitter Saturation Voltage | I _C = 5A; I _B = 0.5A | | | 2.0 | V |
| I _{CBO} | Collector Cutoff Current | V _{CB} = 80V; I _E = 0 | | | 0.1 | mA |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = 7V; I _C = 0 | | | 0.1 | mA |
| h _{FE} | DC Current Gain | Ic= 2A; Vc= 5V | 40 | | | |

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